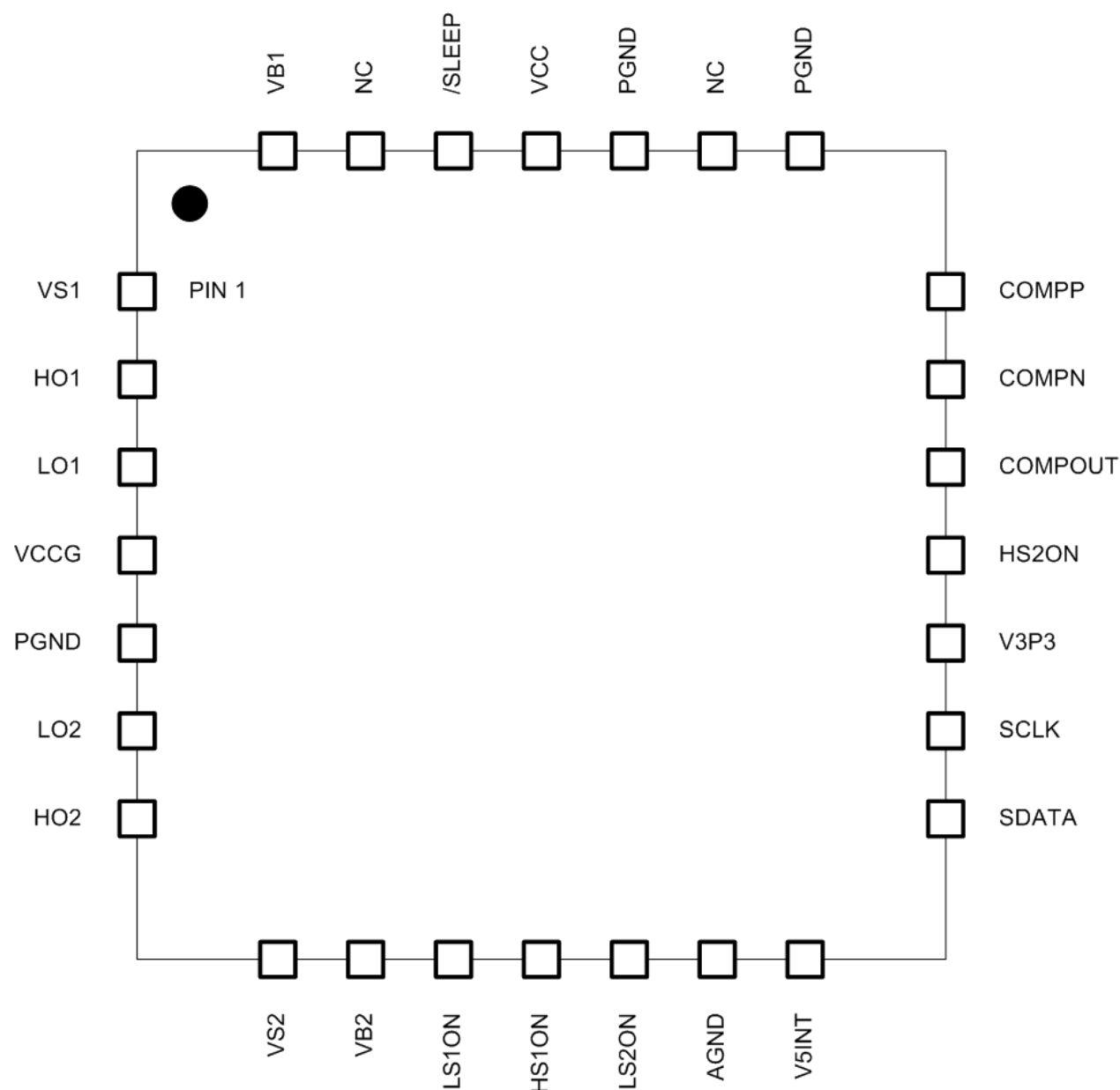


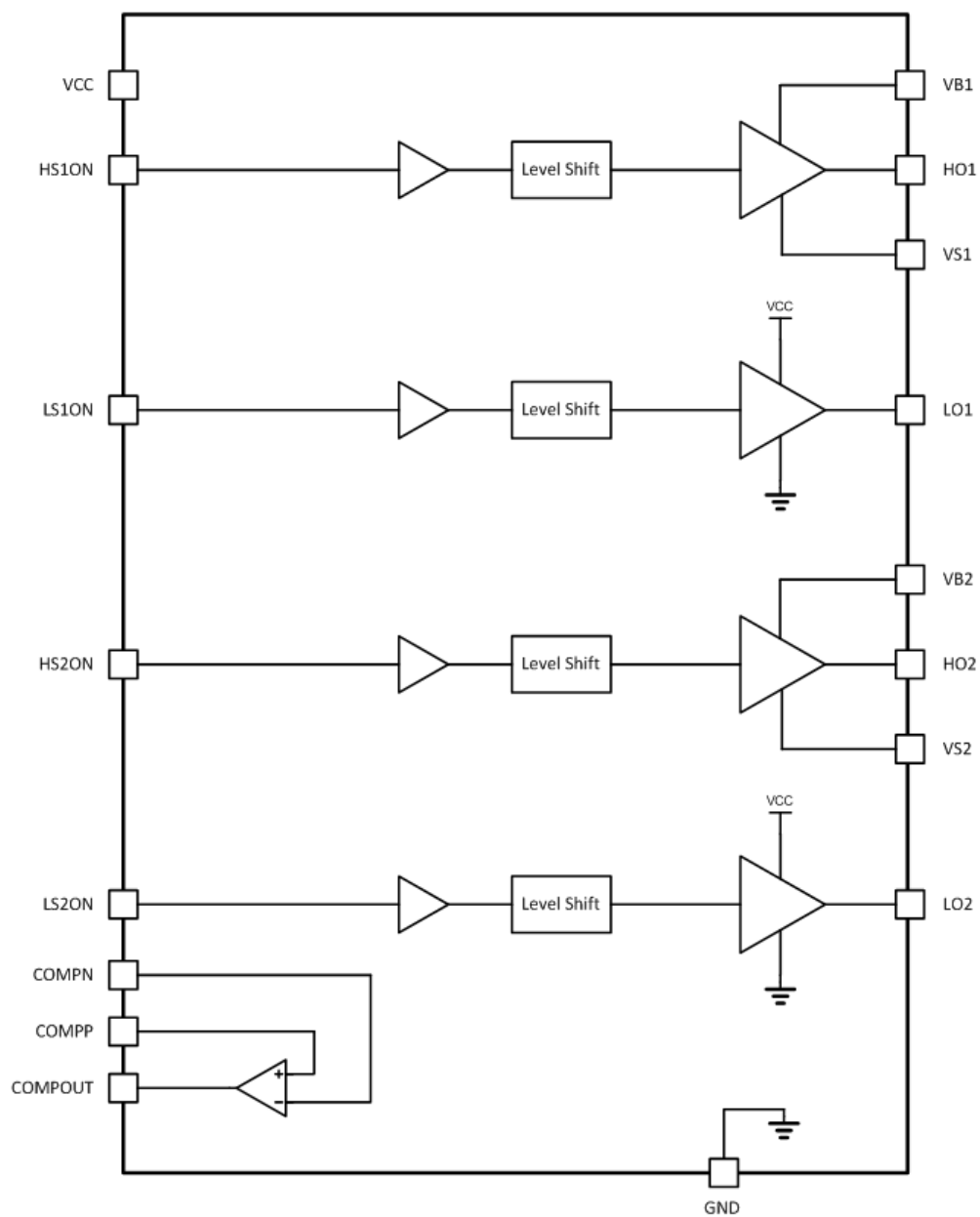
Pinout (Top View)



Pin Description

Pin #	Pin Name	Pin Function	Description
1	VS1	FET drive	High side MOSFET source #1
2	HO1	FET drive	High side MOSFET gate drive #1
3	LO1	FET drive	Low side MOSFET gate drive #1
4	VCCG	Input power	Input power supply (gate drive supply)
5	PGND	Power GND	Power GND
6	LO2	FET drive	Low side MOSFET gate drive #2
7	HO2	FET drive	High side MOSFET gate drive #2
8	VS2	FET drive	High side MOSFET source #2
9	VB2	Bootstrap	Bootstrap for gate drive #2
10	LS1ON	PWM1_L	Low-side gate control #1
11	HS1ON	PWM1_H	High-side gate control #1
12	LS2ON	PWM2_L	Low-side gate control #2
13	AGND	Analog GND	Analog GND
14	V5INT	Decoupling	Internal 5V regulator decoupling
15	SDATA	I2C Data	I2C data
16	SCLK	I2C Clock	I2C clock
17	V3P3	Decoupling	Internal 3.3V regulator decoupling
18	HS2ON	PWM2_H	High-side gate control #2
19	COMPOUT	Comparator	Comparator output
20	COMP_N	Comparator	Comparator input (-)
21	COMPP	Comparator	Comparator input (+)
22	PGND	Power GND	Power GND
23	NC	No Connect	No Connect
24	PGND	Power GND	Power GND
25	VCC	Input power	Input power supply (main device supply)
26	/SLEEP	Disable	Disable Pin (active low)
27	NC	No Connect	No Connect
28	VB1	Bootstrap	Bootstrap for gate drive #1

Functional Block Diagram



Absolute Maximum Rating

Over operating free-air temperature range unless otherwise noted^(1, 2)

Parameter	Value	Unit
VCCG, VCC	13.2	V
VB1, VB2	13.2 (relative to VS1, VS2)	V
SDATA, SCLK	3.6	V
LS1ON, LS2ON, HS1ON, HS2ON	3.6	V
COMPn, COMPP, COMPOUT	3.6	V
Electrostatic Discharge – Human Body Model	+/-2k	V
Electrostatic Discharge – Charge Device Model	+/-500	V
Lead Temperature (soldering, 10 seconds)	260	°C

Notes:

- (1) Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network ground terminal.

Thermal Characteristics

Symbol	Parameter	Value	Units
Θ_{JA}	Thermal Resistance Junction to Air (Note 1)	34.5	°C/W
Θ_{JC}	Thermal Resistance Junction to Case (Note 1)	2.5	°C/W
T_{STG}	Storage Temperature Range	-65 to 150	°C
T_{JMAX}	Maximum Junction Temperature	150	°C
T_J	Operating Junction Temperature Range	-40 to 125	°C

Note 1: Assumes I6LD 3x3 QFN with hi-K JEDEC board and 13.5 inch² of 1 oz Cu and 4 thermal vias connected to PAD

Recommended Operating Conditions

Symbol	Parameter	Min	Typ	Max	Unit
VCCG / VCC	Input Operating Voltage	5	8	12.5	V
C_{VCCBYP}	VCCG / VCC Bypass Capacitors		100		nF
			10		uF
C_{3P3BYP}	Internal 3.3V Bypass Capacitor		4.7		uF
$C_{V5INTBYP}$	Internal 5V Bypass Capacitor		100		nF
C_{BST}	Bootstrap Capacitor		47		nF

Electrical Characteristics

Electrical Characteristics, $T_j = -40^{\circ}\text{C}$ to 125°C , $V_{CC} = 12\text{V}$ (unless otherwise noted)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
VCC Supply Voltage						
V_{CCG} / V_{CC}	Input Supply Voltage		5	8	12.5	V
I_q	Input Supply current	/SLEEP = Hi; No loads; Gate drivers off	0.5	1.5	3	mA
I_q	Input Supply current	/SLEEP = Hi; Gate driver $F_s = 200\text{KHz}$ (no load)		4	5	mA
I_{qq_sleep}	Stand by current	/SLEEP = 0V; Inputs driven Low		3	10	μA
Ron Characteristics						
R_{on} (pulldown)	HS,LS pull down device	$V_{CCG}/V_{CC} = 12\text{V}$		1.4	2	Ω
R_{on} (pullup)	HS, LS pull up device	$V_{CCG}/V_{CC} = 12\text{V}$		4.0	6.5	Ω
Under Voltage Lock Out						
UVLO (rise)	UV threshold (V_{CCG})	Rising threshold measurement	4.1	4.35	4.5	V
UVLO (fall)	UV threshold (V_{CCG})	Falling threshold measurement	3.8	4	4.3	V
UVLO (hyst)	UV hysteresis (V_{CCG})	Hysteresis		0.15	0.25	V
UVLO (rise)	UV threshold (V_{CC})	Rising threshold measurement	4.1	4.35	4.5	V
UVLO (fall)	UV threshold (V_{CC})	Falling threshold measurement	3.8	4	4.3	V
UVLO (hyst)	UV hysteresis (V_{CC})	Hysteresis		0.15	0.25	V
Input Pins VIH & VIL						
V_{IH}	Digital Input Pins	Gate driver inputs, I2C		1.5	2.2	V
V_{IL}	Digital Input Pins	Gate driver inputs, I2C	0.8	1.3		V
Hyst	Digital Input Pins	Gate driver inputs, I2C	0.1	0.2		V
Propagation Delays & Rise/Fall times						
T_{PLShl}	Prop delay (LS) high to low	LSxON to LO1 (11V)		15	50	nS
T_{PLSh}	Prop delay (LS) low to high	LSxON to LO1(1V)		15	50	nS
T_{PHShl}	Prop delay (HS) high to low	HSxON to HOx ($HOx - V_{Sx} = 10\text{V}$)		25	50	nS
T_{PHSh}	Prop delay (HS) low to high	HSxON to HOx ($HOx - V_{Sx} = 1\text{V}$)		25	50	nS
$T_{PMMlshs}$	Prop delay mismatch (ls to hs)	LS off to HS on mismatch		10	40	nS
$T_{PMMhsls}$	Prop delay mismatch (hs to ls)	HS off to LS on mismatch		10	40	nS
T_{PWmin}		Minimum pulse width response		80		nS
T_r	Rise time (HS/LS)	1nF load; 20 – 80%			20	nS
T_p	Fall time (HS/LS)	1nF load; 80 – 20%			20	nS
V3P3 Regulator						
V_{out}	Nominal Output voltage		3.15	3.3	3.45	V
I_{out}	External loading	Output Current capability	10	15		mA
Comparator						
V_{offset}	Comparator Offset		-10	0	10	mV
V_{CMin}	Input Common Mode Range		0.2		1.8	V
T_{comp}	Comparator detection time	Input signal of 10mV		40	80	nS

Application Schematic

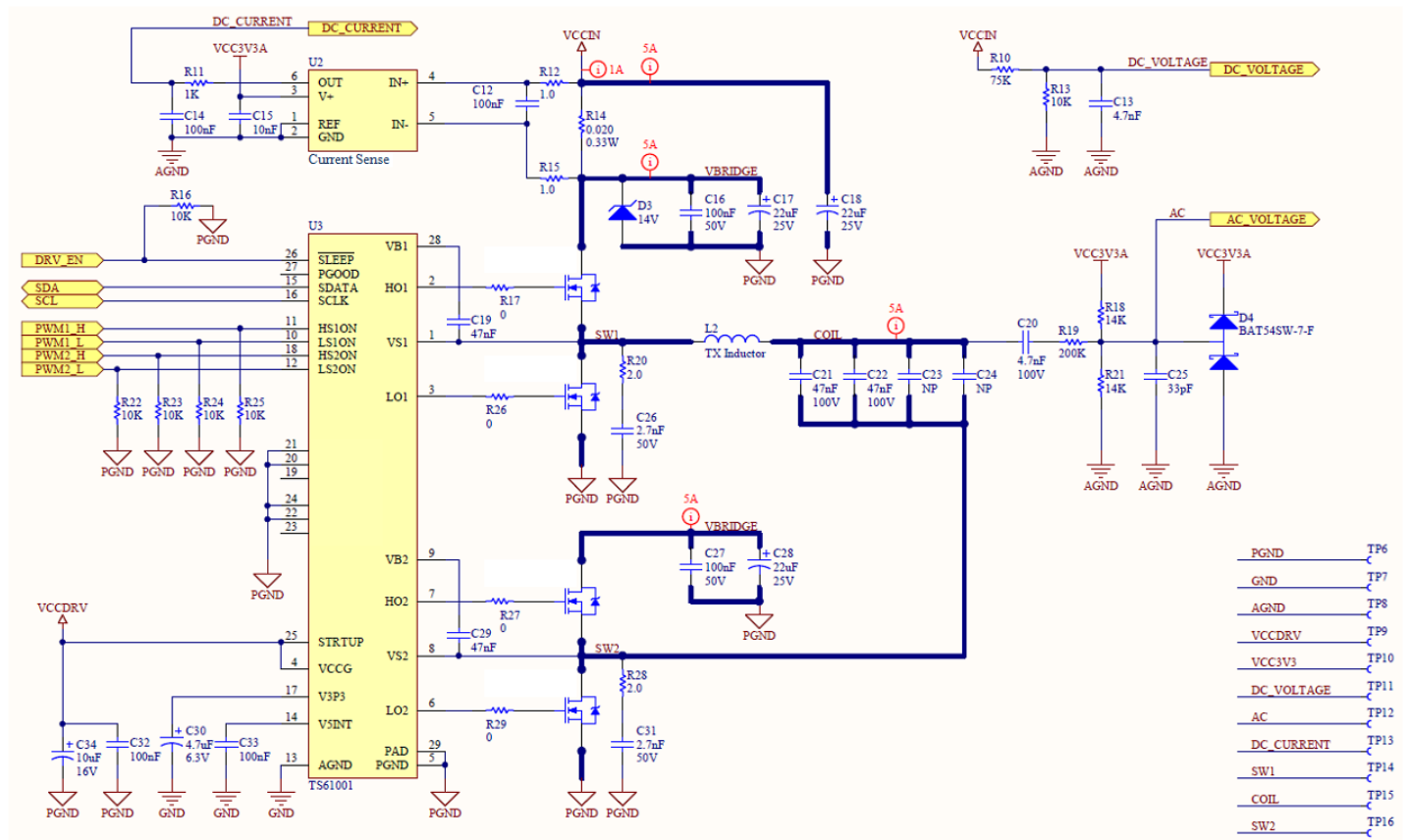
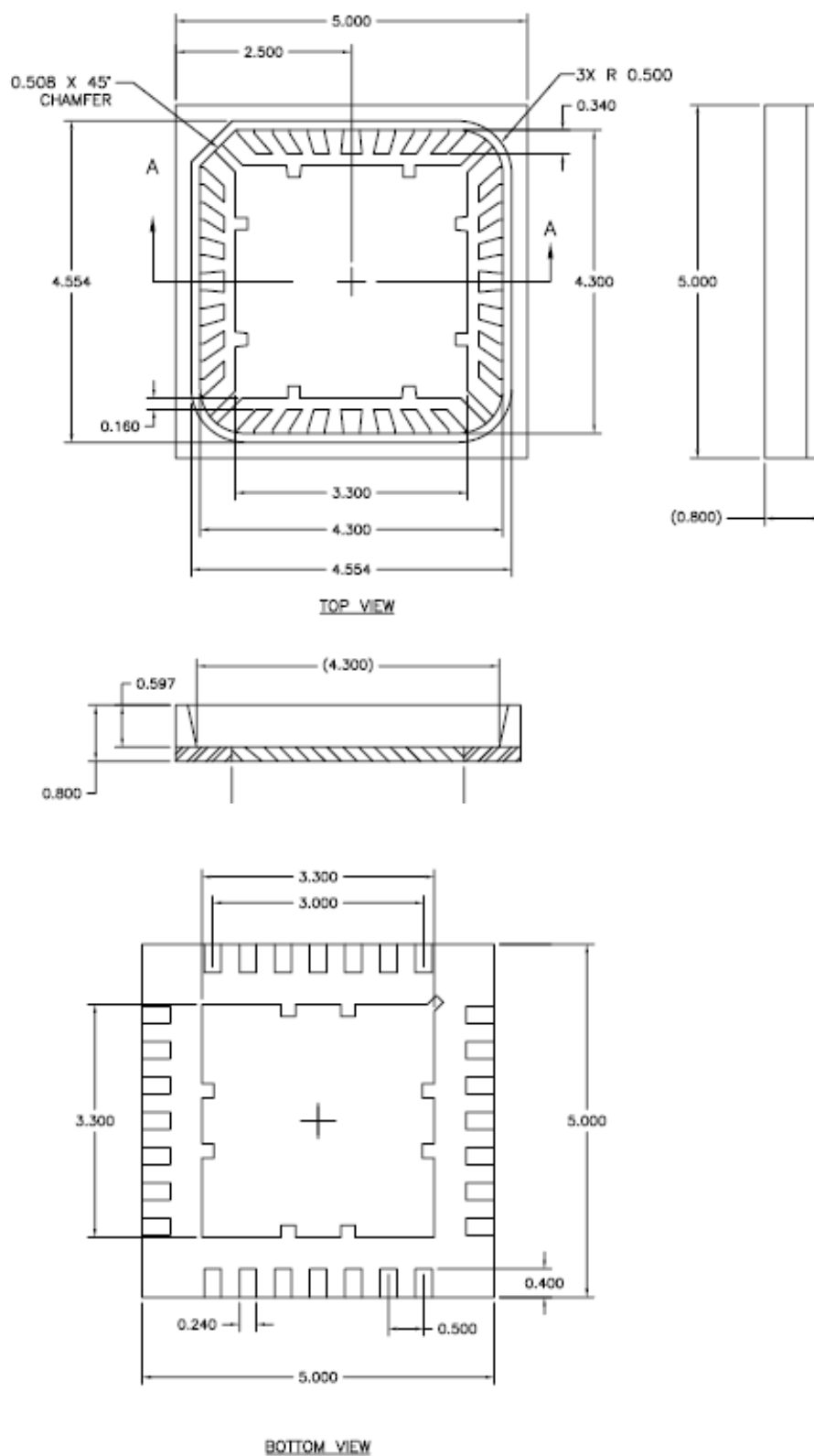


Figure 1: TS61001 Application Schematic

Package Dimensions



Ordering Information

Part Number	Description
TS61001-QFNR	Full-bridge FET Driver

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- Hydrochlorofluorocarbons (HCFCs)
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